

# Diode Lasers, Single-mode 50 to 200 mW, 810/830/852 nm 54xx Series



Key Features

• Narrow spectral width

• 200 mW kink-free power

- High efficiency
- Low astigmatism
- High reliability

## Applications

- Illumination
- Printing
- Sensing
- Medical applications
- Imaging

High-resolution applications including optical data storage, image recording, spectral analysis, printing, point-to-point free-space communications and frequency doubling all require diffraction-limited sources. Faster writing, wider dynamic range and better signal-to-noise ratio may be achieved with JDSU's high-reliability 5400 Series single-mode diode lasers.

Available in power levels up to 200 mW kink-free, this advanced diode laser combines a quantum well structure and a real-refractive index-guided single-mode waveguide to provide high power, low astigmatism, narrow spectral width and a single spatial mode Gaussian far field. Our 5400 Series diode lasers are among the most reliable high-power diode lasers available in the industry today.

The 5400 Series diode lasers operate in single longitudinal mode under some conditions. Like in all Fabry-Perot index-guided diode lasers, spectral broadening, mode hopping and longitudinal mode instability may occur due to small changes in drive current, diode-junction temperature or optical feedback.

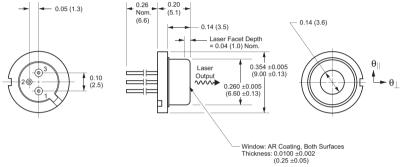
The unique diode structure features high reliability with long operating life and very low early failure rate. The highest brightness (20 MW/cm<sup>2</sup> steradian) is provided by our 5430.

**54XX SERIES DIODE LASERS** 

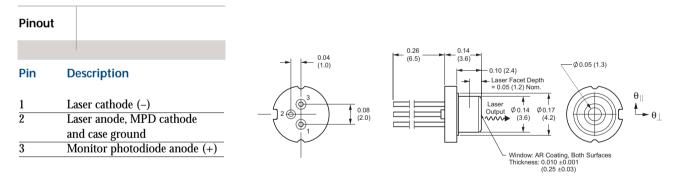
# 2

Package Style: SOT-148 Window (G1)	Dimensions Diagrams	(Specifications in inches [ Standard Tolerances inches: x.xx = ±0.02 x.xxx = ±0.010	mm] unless otherwise noted.) mm: x.x = ±0.5 x.xx = ±0.25	
	Package Style: SOT-148 Window (G1)			
Pinout	Pinout		Nom. (5.1) (6.6)	

Pin	Description
1	Laser cathode (-)
2	Laser anode, MPD cathode and case ground
3	Monitor photodiode anode (+)



Package Style: TO-56 Window (J1)



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Available Configurations	<b>5400 Series</b>	<b>5410 Series</b>	<b>5420 Series</b>	<b>5430 Series</b>
	5401-G1	5411-G1	5421-G1	5431-G1
	5401-J1	5411-J1	5421-J1	5431-J1

# **Electro-optical Specifications**

Parameter	Symbol	54	00 Series		5	410 Serie	S	Unit
		Min.	Тур.	Max.	Min.	Тур.	Max.	
Laser Characteristics								
CW output power, kink-free <sup>2</sup>	Po	-	-	50	-	-	100	mW
Center wavelength	$\lambda_{c}$	-	(note <sup>5</sup> )	-	-	(note <sup>5</sup> )	-	
Spectral width <sup>1</sup>	Δλ	-	3	5	-	3	5	nm
Slope efficiency	$\eta D = P_0/(I_{op}-I_{th})$	0.75	0.85	-	0.75	0.85	-	mW/mA
Conversion efficiency	$\eta = P_0/(I_{op}V_{op})$	-	30	-	-	30	-	%
Emitting dimensions	WxH	-	3 x 1	-	-	3 x 1	-	μm
FWHM beam divergence								
Parallel to junction	θ//	-	9	-	-	9	-	degrees
Perpendicular to junction	θ	-	30	-	-	30	-	degrees
Threshold current	Ith	-	35	45	-	35	45	mA
Operating current	I <sub>op</sub>	-	95	105	-	160	170	mA
Operating voltage	V <sub>op</sub>	-	(note <sup>4</sup> )	-	-	(note <sup>4</sup> )	-	
Series resistance	Rs	-	4.0	6.0	-	4.0	6.0	Ω
Thermal resistance	Rth	-	60	-	-	60	-	°C/W
Recommended case temperature	T <sub>C</sub>	-20	-	30	-20	-	30	°C
Absolute Maximum Ratings								
Reverse voltage	V <sub>rl</sub>	-	_	3	-	-	3	V
Case operating temperature	Тор	-20	-	50	-20	-	50	°C
Storage temperature range	Tstg	-40	-	80	-40	-	80	°C
Lead soldering temperature	T <sub>is</sub>	-	-	250	-	-	250	°C (5 sec.
Monitor Photodiode								
Sensitivity								
G1 package	-	0.1	-	20	0.1	-	20	μA/mW
J1 package	-	3.0	-	24	3.0	-	24	μA/mW
Capacitance	-	-	6	_	-	6	_	pF
Breakdown voltage	Vbd	-	25	-	-	25	-	V
Operating voltage	Vop	-	10	_	_	10	-	V

- Emission bandwidth for 90% integrated power.
   Typical values at 25 °C and 0.6 NA collection optics.
   Features common to all 5400 series diode lasers include:

   a. Duty factor of 100%.
   b. Temperature coefficient of wavelength is approximately 0.3 nm/°C.
   c. Temperature coefficient of threshold current can be modeled as: Ir<sub>H2</sub> = Ir<sub>H1</sub> exp [(T<sub>2</sub> T<sub>1</sub>)/T<sub>0</sub>] where T<sub>0</sub> is a device constant of about 110 °K.
   d. Temperature coefficient of operating current is approximately 0.5 to 0.7% per °C.

   Forward voltage is typically: V<sub>f</sub> = 1.5 V + I<sub>op</sub> x R<sub>s</sub>.
   Wavelength ranges for the 5400 and 5410 series: 800-820 nm 810-850 nm

810-850 nm

842-862 nm

A variety of part numbers are available that each designate a particular subset within these wavelength ranges. Consult tables on page 5. 6. Astigmatism is less than 5  $\mu$ m.

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# **Electro-optical Specifications**

Continued

Parameter	Symbol	54	20 Series	1	5	430 Serie	S	Unit
		Min.	Тур.	Max.	Min.	Тур.	Max.	
Laser Characteristics								
CW output power, kink-free <sup>2</sup>	Po	-	-	150	_	-	200	mW
Center wavelength	$\lambda_{c}$	-	(note <sup>5</sup> )	-	-	(note <sup>5</sup> )	-	
Spectral width <sup>1</sup>	Δλ	-	3	5	_	3	5	nm
Slope efficiency	$\eta D = P_0/(I_{op}-I_{th})$	0.75	0.85	-	0.75	0.85	-	mW/mA
Conversion efficiency	$\eta = P_0/(I_{op}V_{op})$	-	30	-	_	30	-	%
Emitting dimensions	WxH	-	3 x 1	-	_	3 x 1	-	μm
FWHM beam divergence								
Parallel to junction	θ//	-	9	-	-	9	-	degrees
Perpendicular to junction	$\theta_{\perp}$	-	30	-	-	30	-	degrees
Threshold current	I <sub>th</sub>	-	35	45	-	40	50	mA
Operating current	Iop	_	210	230	_	270	300	mA
Operating voltage	Vop	-	(note <sup>4</sup> )	-	_	(note <sup>4</sup> )	-	
Series resistance	R <sub>s</sub>	-	4.0	6.0	-	4.0	6.0	Ω
Thermal resistance	Rth	-	60	-	_	60	-	°C/W
Recommended case temperature	T <sub>C</sub>	-20	-	30	-20	-	30	°C
Absolute Maximum Ratings								
Reverse voltage	Vrl	-	-	3	-	-	3	V
Case operating temperature	Top	-20	-	50	-20	-	50	°C
Storage temperature range	Tstg	-40	-	80	-40	-	80	°C
Lead soldering temperature	T <sub>is</sub>	_	-	250	_	-	250	°C (5 sec.)
Monitor Photodiode								
Sensitivity	-	0.1	-	20	0.1	-	20	μA/mW
Capacitance	-	_	6	-		6	-	pF
Breakdown voltage	Vbd	_	25	-		25	-	
Operating voltage	Vop	-	10	_		10	_	V

Emission bandwidth for 90% integrated power.
 Typical values at 25 °C and 0.6 NA collection optics.
 Features common to all 5400 series diode lasers include:

 a. Duty factor of 100%.
 b. Temperature coefficient of wavelength is approximately 0.3 nm/°C.
 c. Temperature coefficient of threshold current can be modeled as: ITH2 = ITH1 exp [(T2 - T1)/T0] where T0 is a device constant of about 110 °K.
 d. Temperature coefficient of operating current is approximately 0.5 to 0.7% per °C.

 Forward voltage is typically: Vf = 1.5 V + Iop x Rs.
 Wavelength ranges for the 5420 series: 800-820 nm 810-850 nm

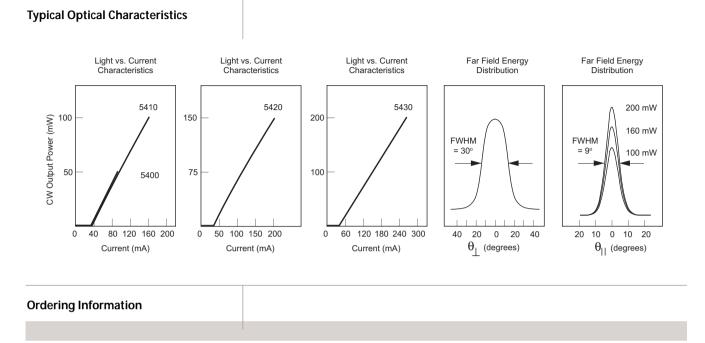
810-850 nm

842-862 nm

Wavelength range for the 5430 series is limited to 820-840 nm. A variety of part numbers are available that each designate a particular subset within these wavelength ranges. Consult tables on page 5.

6. Astigmatism is less than 5  $\mu$ m.

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For more information on this or other products and their availability, please contact your local JDSU account manager or JDSU directly at 1-800-498-JDSU (5378) in North America and +800-5378-JDSU worldwide or via e-mail at customer.service@jdsu.com.

#### Sample: 54-00202

Part Number	Power	Wavelength	Package	
54-00202	50 mW	810 (±5)	5.6 mm TO-56	
54-00203	50 mW	830 (-10/+20)	5.6 mm TO-56	
Call for part number	50 mW	830 (-10/+20)	9 mm SOT-148	
54-00204	50 mW	852 (±10)	5.6 mm TO-56	
54-00205	100 mW	810 (±5)	5.6 mm TO-56	
54-00206	100 mW	830 (-10/+20)	5.6 mm TO-56	
54-00207	100 mW	852 (±10)	5.6 mm TO-56	
Call for part number	150 mW	810 (±5)	9 mm SOT-148	
54-00210	150 mW	810 (±5)	5.6 mm TO-56	
Call for part number	150 mW	830 (±10)	9 mm SOT-148	
54-00211	150 mW	830 (±10)	5.6 mm TO-56	
Call for part number	150 mW	852 (±10)	9 mm SOT-148	
54-00212	150 mW	852 (±10)	5.6 mm TO-56	
Call for part number	200 mW	830 (±10)	9 mm SOT-148	
54-00213	200 mW	830 (±10)	5.6 mm TO-56	
54-00214	200 mW	852 (±10)	5.6 mm TO-56	



User Safety

## Safety and Operating Considerations

The laser light emitted from this diode laser is invisible and may be harmful to the human eye. Avoid looking directly into the diode laser or into the collimated beam along its optical axis when the device is in operation.

CAUTION: THE USE OF OPTICAL INSTRUMENTS WITH THIS PRODUCT WILL INCREASE EYE HAZARD.

Operating the diode laser outside of its maximum ratings may cause device failure or a safety hazard. Power supplies used with the component must be employed such that the maximum peak optical power cannot be exceeded. CW diode lasers may be damaged by excessive drive current or switching transients. When using power supplies, the diode laser should be connected with the main power on and the output voltage at zero. The current should be increased slowly while monitoring the diode laser output power and the drive current.

Device degradation accelerates with increased temperature, and therefore careful attention to minimize the case temperature is advised. For example, life expectancy will decrease by a factor of four if the case is operated at 50 °C rather than 30 °C.

A proper heatsink for the diode laser on a thermal radiator will greatly enhance laser life. Firmly mount the laser on a radiator with a thermal impedance of less than 2 °C/W for increased reliability.

ESD PROTECTION – Electrostatic discharge is the primary cause of unexpected diode laser failure. Take extreme precaution to prevent ESD. Use wrist straps, grounded work surfaces and rigorous antistatic techniques when handling diode lasers.

Labeling	

## 21 CFR 1040.10 Compliance

Because of the small size of these devices, each of the labels shown is attached to the individual shipping container. They are illustrated here to comply with 21 CFR 1040.10 as applicable under the Radiation Control for Health and Safety Act of 1968.

## Serial Number Identification Label

JDS Unipha	ase Corporation
MODEL:	S/N:
MANUFACTURED: WAVELENGTH:	l op:
This laser product compli	es with 21 CFR 1040 as applicable

# **Output Power Danger Label**



# **Package Aperture Labels**



G1, J1 Package Diodes

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